



BC847BVC

NPN DUAL SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- $BV_{CEO} > 45V$
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 @3)
- Weight 0.002 grams (Approximate)







Top View

Bottom View

Device Schematic

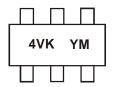
Ordering Information (Note 4)

| Product | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|------------|------------|---------|--------------------|-----------------|-------------------|
| BC847BVC-7 | AEC-Q101 | 4VK | 7 | 8mm | 3,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



4VK = Product Type Marking Code YM = Date Code Marking Y = Year (ex: E = 2017)M = Month (ex: 9 = September)

Date Code Key

| 2010 0000 1 | , | | | | | | | | | | | | |
|-------------|------|------|------|------|-----|------|-----|----|-----|------|------|------|------|
| Year | 2017 | 2018 | 2019 | 2020 | 202 | 21 2 | 022 | 20 | 23 | 2024 | 2025 | 2026 | 2027 |
| Code | E | F | G | Н | | | J | k | < | L | М | N | 0 |
| Month | Jan | Feb | Mar | Apr | May | Jun | Ju | ıl | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | ' | 8 | 9 | 0 | N | D |

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Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---------------------------|------------------|-------|------|
| Collector-Base Voltage | V_{CBO} | 50 | V |
| Collector-Emitter Voltage | V _{CEO} | 45 | V |
| Emitter-Base Voltage | V_{EBO} | 6.0 | V |
| Collector Current | lc | 100 | mA |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 5) | P_{D} | 150 | mW |
| Thermal Resistance, Junction to Ambient (Note 5) | $R_{	heta JA}$ | 833 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

ESD Ratings (Note 6)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | ٧ | ЗА |
| Electrostatic Discharge - Machine Model | ESD MM | 200 | V | В |

Notes: 5. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch.

^{6.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information

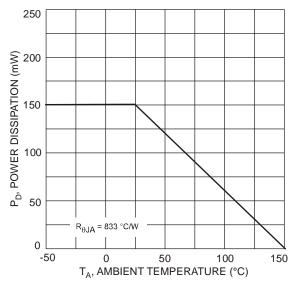


Fig. 1 Power Dissipation vs. Ambient Temperature

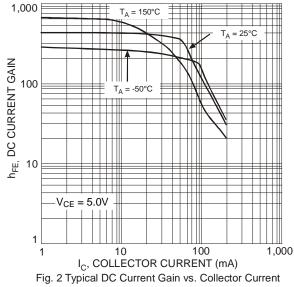
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Min | Тур | Max | Unit | Test Condition |
|--------------------------------------|----------|----------------------|----------|------------|------------|----------|---|
| Collector-Base Breakdown Voltage | | | 50 | _ | _ | V | $I_C = 10\mu A, I_B = 0$ |
| Collector-Emitter Breakdown Voltage | | V _{(BR)CEO} | 45 | _ | _ | V | $I_C = 10mA, I_B = 0$ |
| Emitter-Base Breakdown Voltage | | $V_{(BR)EBO}$ | 6 | _ | _ | V | $I_E = 1\mu A, I_C = 0$ |
| DC Current Gain | (Note 7) | h _{FE} | 200 | 290 | 450 | | $V_{CE} = 5.0V, I_{C} = 2.0mA$ |
| Collector-Emitter Saturation Voltage | (Note 7) | V _{CE(SAT)} | 1 | | 100 300 | mV | $I_C = 10\text{mA}, I_B = 0.5\text{mA}$ $I_C = 100\text{mA}, I_B = 5.0\text{mA}$ |
| Base-Emitter Saturation Voltage | (Note 7) | V _{BE(SAT)} | 1 | 700 900 | _ | mV | $I_C = 10\text{mA}, I_B = 0.5\text{mA}$ $I_C = 100\text{mA}, I_B = 5.0\text{mA}$ |
| Base-Emitter Voltage | | V_{BE} | 580 — | 660 — | 700 770 | mV | $V_{CE} = 5.0V, I_{C} = 2.0mA$ $V_{CE} = 5.0V, I_{C} = 10mA$ |
| Collector-Emitter Cutoff Current | | I _{CBO} | 1 | | 15 5.0 | nΑ μΑ | V _{CB} = 30V V _{CB} = 30V, T _A = +150°C |
| Gain Bandwidth Product | | f⊤ | 100 | _ | _ | MHz | $V_{CE} = 5.0V$, $I_{C} = 10mA$, $f = 100MHz$ |
| Output Capacitance | | C _{OBO} | | _ | 4.5 | pF | $V_{CB} = 10V, f = 1.0MHz$ |
| Noise Figure | | NF | _ | _ | 10 | dB | $V_{CE} = 5V, R_S = 2.0k\Omega,$ f = 1.0kHz, BW = 200Hz |

Note: 7. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.



Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



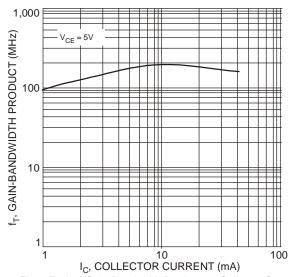


Fig. 4 Typical Gain-Bandwidth Product vs. Collector Current

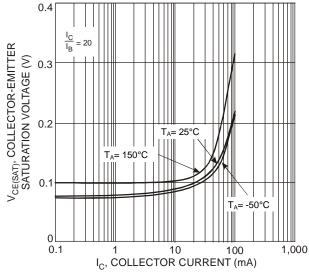


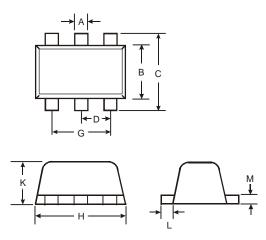
Fig. 3 Typical Collector Emitter Saturation Voltage vs. Collector Current



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563

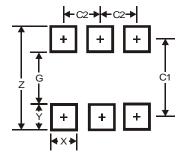


| SOT563 | | | | | | |
|----------------------|------|------|------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.15 | 0.30 | 0.20 | | | |
| В | 1.10 | 1.25 | 1.20 | | | |
| С | 1.55 | 1.70 | 1.60 | | | |
| D | - | - | 0.50 | | | |
| G | 0.90 | 1.10 | 1.00 | | | |
| Н | 1.50 | 1.70 | 1.60 | | | |
| K | 0.55 | 0.60 | 0.60 | | | |
| L | 0.10 | 0.30 | 0.20 | | | |
| М | 0.10 | 0.18 | 0.11 | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.2 |
| G | 1.2 |
| Х | 0.375 |
| Y | 0.5 |
| C1 | 1.7 |
| C2 | 0.5 |



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